



## 3. High-D Consortium Meeting

### Friday 10 February 2023

#### Radiation effects (11:20 - 13:00)

time	[id] title	presenter
11:20	[68] Investigation of high resistivity p-type FZ silicon diodes after 60Co - □ irradiation	LIAO, Chuan
11:40	[71] Latest results from irradiated DPTS sensors produced in 65 nm CMOS technology	BECHT, Pascal
12:00	[72] Radiation tolerance of the MIMOSIS-1 CMOS sensor	DEVEAUX, Michael
12:20	[67] Study of the self-heating in SiPMs	VILLALBA PETRO, Carmen Victoria